

TELUX™ LED

| Color | Type | Technology | Angle of Half Intensity $\pm\varphi$ |
|------------|-----------|--------------------|---|
| Red | TLWR76.. | AllnGaP on GaAs | 30° |
| Yellow | TLWY76.. | AllnGaP on GaAs | |
| Softorange | TLWO76.. | AllnGaP on GaAs | |
| True Green | TLWTG76.. | InGaN on SiC | |
| Blue Green | TLWBG76.. | InGaN on SiC | |
| Blue | TLWB76.. | InGaN on SiC | |
| White | TLWW76.. | InGaN / YAG on SiC | |

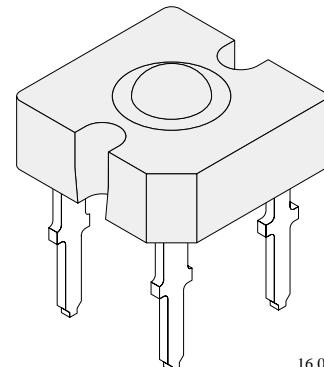
Description

The TELUX™ series is a clear, non diffused LED for high end applications where supreme luminous flux is required.

It is designed in an industry standard 7.62 mm square package utilizing highly developed (AS) AllnGaP and InGaN technologies.

The supreme heat dissipation of TELUX™ allows applications at high ambient temperatures.

All packing units are binned for luminous flux and color to achieve best homogenous light appearance in application.



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Features

- Utilizing (AS) AllnGaP and InGaN technologies
- High luminous flux
- Supreme heat dissipation: R_{thJP} is 90 K/W
- High operating temperature: T_j up to + 125 °C
- Type TLWR meets SAE and ECE color requirements
- Packed in tubes for automatic insertion
- Luminous flux and color categorized for each tube
- Small mechanical tolerances allow precise usage of external reflectors or lightguides
- TLWR and TLWY types additionally forward voltage categorized
- ESD-withstand voltage:
>> 2 kV acc. to MIL STD 883 D, Method 3015.7 for AllnGaP, > 1 kV for InGaN

Applications

Exterior lighting
 Dashboard illumination
 Tail-, Stop – and Turn Signals of motor vehicles
 Replaces incandescent lamps
 Traffic signals and signs

Absolute Maximum Ratings $T_{amb} = 25^\circ C$, unless otherwise specified

TLWR76.. , TLWY76.. , TLWO76.. ,

| Parameter | Test Conditions | Type | Symbol | Value | Unit |
|-------------------------------------|---|----------------------------------|------------|-------------|------|
| Reverse voltage | $I_R = 10\mu A$ | TLWR76.. TLWY76.. TLWO76.. | V_R | 10 | V |
| DC forward current | $T_{amb} \leq 85^\circ C$ | | I_F | 70 | mA |
| Surge forward current | $t_p \leq 10 \mu s$ | | I_{FSM} | 1 | A |
| Power dissipation | $T_{amb} \leq 85^\circ C$ | | P_V | 187 | mW |
| Junction temperature | | | T_j | 125 | °C |
| Operating temperature range | | | T_{amb} | -40 to +110 | °C |
| Storage temperature range | | | T_{stg} | -55 to +110 | °C |
| Soldering temperature | $t \leq 5 s$, 1.5 mm from body pre-heat temperature $100^\circ C / 30sec.$ | | T_{sd} | 260 | °C |
| Thermal resistance junction/ambient | with cathode heatsink of 70 mm^2 | | R_{thJA} | 200 | K/W |
| Thermal resistance junction/pin | | | R_{thJP} | 90 | K/W |

 $T_{amb} = 25^\circ C$, unless otherwise specified

TLWTG76.. , TLWBG76.. , TLWB76.. , TLWW76.. ,

| Parameter | Test Conditions | Type | Symbol | Value | Unit |
|-------------------------------------|--|--|------------|-------------|------|
| Reverse voltage | $I_R = 10\mu A$ | TLWTG76.. TLWBG76.. TLWB76.. TLWW76.. | V_R | 5 | V |
| DC forward current | $T_{amb} \leq 50^\circ C$ | | I_F | 50 | mA |
| Surge forward current | $t_p \leq 10 \mu s$ | | I_{FSM} | 0.1 | A |
| Power dissipation | $T_{amb} \leq 50^\circ C$ | | P_V | 230 | mW |
| | | | P_V | 255 | mW |
| Junction temperature | | | T_j | 100 | °C |
| Operating temperature range | | | T_{amb} | -40 to +100 | °C |
| Storage temperature range | | | T_{stg} | -55 to +100 | °C |
| Soldering temperature | $t \leq 5 s$, 1.5 mm from body preheat temperature $100^\circ C / 30sec.$ | | T_{sd} | 260 | °C |
| Thermal resistance junction/ambient | with cathode heatsink of 70 mm^2 | | R_{thJA} | 200 | K/W |
| Thermal resistance junction/pin | | | R_{thJP} | 90 | K/W |

Optical and Electrical Characteristics

T_{amb} = 25°C, unless otherwise specified

Red (TLWR76..)

| Parameter | Test Conditions | Type | Symbol | Min | Typ | Max | Unit |
|--|--|------|----------------------|------|----------|------|---------|
| Total flux | $I_F = 70 \text{ mA}, R_{thJA}=200 \text{ }^\circ\text{K/W}$ | | ϕ_V | 1500 | 2100 | 3000 | mlm |
| Luminous intensity/Total flux | | | I_V/ϕ_V | | 0.8 | | mcd/mlm |
| Dominant wavelength | | | λ_d | 611 | 618 | 634 | nm |
| Peak wavelength | | | λ_p | | 624 | | nm |
| Angle of half intensity | | | φ | | ± 30 | | deg |
| Total included angle | 90 % of Total Flux Captured | | $\phi_{0.9V}$ | | 75 | | deg |
| Forward voltage | $I_F = 70 \text{ mA}, R_{thJA}=200 \text{ }^\circ\text{K/W}$ | | V_F | 1.83 | 2.2 | 2.67 | V |
| Reverse voltage | $I_R = 10 \mu\text{A}$ | | V_R | 10 | 20 | | V |
| Junction capacitance | $V_R = 0, f = 1 \text{ MHz}$ | | C_j | | 17 | | pF |
| Temperature coefficient of λ_{dom} | $I_F = 50 \text{ mA}$ | | $TC_{\lambda_{dom}}$ | | 0.05 | | nm/K |

Softorange (TLWO76..)

| Parameter | Test Conditions | Type | Symbol | Min | Typ | Max | Unit |
|--|--|------|----------------------|------|----------|------|---------|
| Total flux | $I_F = 70 \text{ mA}, R_{thJA}=200 \text{ }^\circ\text{K/W}$ | | ϕ_V | 1500 | 2100 | 3000 | mlm |
| Luminous intensity/Total flux | | | I_V/ϕ_V | | 0.8 | | mcd/mlm |
| Dominant wavelength | | | λ_d | 598 | 605 | 611 | nm |
| Peak wavelength | | | λ_p | | 610 | | nm |
| Angle of half intensity | | | φ | | ± 30 | | deg |
| Total included angle | 90 % of Total Flux Captured | | $\phi_{0.9V}$ | | 75 | | deg |
| Forward voltage | $I_F = 70 \text{ mA}, R_{thJA}=200 \text{ }^\circ\text{K/W}$ | | V_F | 1.83 | 2.2 | 2.67 | V |
| Reverse voltage | $I_R = 10 \mu\text{A}$ | | V_R | 10 | 20 | | V |
| Junction capacitance | $V_R = 0, f = 1 \text{ MHz}$ | | C_j | | 17 | | pF |
| Temperature coefficient of λ_{dom} | $I_F = 50 \text{ mA}$ | | $TC_{\lambda_{dom}}$ | | 0.06 | | nm/K |

Yellow (TLWY76..)

| Parameter | Test Conditions | Type | Symbol | Min | Typ | Max | Unit |
|--|--|------|----------------------|------|----------|------|---------|
| Total flux | $I_F = 70 \text{ mA}, R_{thJA}=200 \text{ }^\circ\text{K/W}$ | | ϕ_V | 1000 | 1400 | 2400 | mlm |
| Luminous intensity/Total flux | | | I_V/ϕ_V | | 0.8 | | mcd/mlm |
| Dominant wavelength | | | λ_d | 585 | 592 | 597 | nm |
| Peak wavelength | | | λ_p | | 594 | | nm |
| Angle of half intensity | | | φ | | ± 30 | | deg |
| Total included angle | 90 % of Total Flux Captured | | $\phi_{0.9V}$ | | 75 | | deg |
| Forward voltage | $I_F = 70 \text{ mA}, R_{thJA}=200 \text{ }^\circ\text{K/W}$ | | V_F | 1.83 | 2.1 | 2.67 | V |
| Reverse voltage | $I_R = 10 \mu\text{A}$ | | V_R | 10 | 15 | | V |
| Junction capacitance | $V_R = 0, f = 1 \text{ MHz}$ | | C_j | | 32 | | pF |
| Temperature coefficient of λ_{dom} | $I_F = 50 \text{ mA}$ | | $TC_{\lambda_{dom}}$ | | 0.1 | | nm/K |

TLW.76..

Vishay Telefunken



True Green (TLWTG76..)

| Parameter | Test Conditions | Type | Symbol | Min | Typ | Max | Unit |
|--|--|------|----------------------|-----|----------|------|---------|
| Total flux | $I_F = 50 \text{ mA}, R_{thJA}=200 \text{ }^\circ\text{K/W}$ | | ϕ_V | 630 | 900 | 1800 | mlm |
| Luminous intensity/Total flux | | | I_V/ϕ_V | | 0.8 | | mcd/mlm |
| Dominant wavelength | | | λ_d | 509 | 523 | 529 | nm |
| Peak wavelength | | | λ_p | | 518 | | nm |
| Angle of half intensity | | | φ | | ± 30 | | deg |
| Total included angle | 90 % of Total Flux Captured | | $\phi_{0.9V}$ | | 75 | | deg |
| Forward voltage | $I_F = 50 \text{ mA}, R_{thJA}=200 \text{ }^\circ\text{K/W}$ | | V_F | | 4.2 | 4.7 | V |
| Reverse voltage | $I_R = 10 \mu\text{A}$ | | V_R | 5 | 10 | | V |
| Junction capacitance | $V_R = 0, f = 1 \text{ MHz}$ | | C_j | | 50 | | pF |
| Temperature coefficient of λ_{dom} | $I_F = 30 \text{ mA}$ | | $TC_{\lambda_{dom}}$ | | 0.02 | | nm/K |

Blue Green (TLWBG76..)

| Parameter | Test Conditions | Type | Symbol | Min | Typ | Max | Unit |
|--|--|------|----------------------|-----|----------|------|---------|
| Total flux | $I_F = 50 \text{ mA}, R_{thJA}=200 \text{ }^\circ\text{K/W}$ | | ϕ_V | 400 | 700 | 1250 | mlm |
| Luminous intensity/Total flux | | | I_V/ϕ_V | | 0.8 | | mcd/mlm |
| Dominant wavelength | | | λ_d | 492 | 505 | 510 | nm |
| Peak wavelength | | | λ_p | | 503 | | nm |
| Angle of half intensity | | | φ | | ± 30 | | deg |
| Total included angle | 90 % of Total Flux Captured | | $\phi_{0.9V}$ | | 75 | | deg |
| Forward voltage | $I_F = 50 \text{ mA}, R_{thJA}=200 \text{ }^\circ\text{K/W}$ | | V_F | | 4.2 | 4.7 | V |
| Reverse voltage | $I_R = 10 \mu\text{A}$ | | V_R | 5 | 10 | | V |
| Junction capacitance | $V_R = 0, f = 1 \text{ MHz}$ | | C_j | | 50 | | pF |
| Temperature coefficient of λ_{dom} | $I_F = 30 \text{ mA}$ | | $TC_{\lambda_{dom}}$ | | 0.02 | | nm/K |

Blue (TLWB76..)

| Parameter | Test Conditions | Type | Symbol | Min | Typ | Max | Unit |
|--|--|------|----------------------|-----|----------|-----|---------|
| Total flux | $I_F = 50 \text{ mA}, R_{thJA}=200 \text{ }^\circ\text{K/W}$ | | ϕ_V | 200 | 330 | 630 | mlm |
| Luminous intensity/Total flux | | | I_V/ϕ_V | | 0.8 | | mcd/mlm |
| Dominant wavelength | | | λ_d | 462 | 470 | 476 | nm |
| Peak wavelength | | | λ_p | | 460 | | nm |
| Angle of half intensity | | | φ | | ± 30 | | deg |
| Total included angle | 90 % of Total Flux Captured | | $\phi_{0.9V}$ | | 75 | | deg |
| Forward voltage | $I_F = 50 \text{ mA}, R_{thJA}=200 \text{ }^\circ\text{K/W}$ | | V_F | | 4.3 | 4.7 | V |
| Reverse voltage | $I_R = 10 \mu\text{A}$ | | V_R | 5 | 10 | | V |
| Junction capacitance | $V_R = 0, f = 1 \text{ MHz}$ | | C_j | | 50 | | pF |
| Temperature coefficient of λ_{dom} | $I_F = 30 \text{ mA}$ | | $TC_{\lambda_{dom}}$ | | 0.03 | | nm/K |

White (TLWW76..)

| Parameter | Test Conditions | Type | Symbol | Min | Typ | Max | Unit |
|-------------------------------|--|------|---------------|-----|----------|------|---------|
| Total flux | $I_F = 50 \text{ mA}, R_{thJA}=200 \text{ }^{\circ}\text{K/W}$ | | ϕ_V | 400 | 650 | 1250 | mlm |
| Luminous intensity/Total flux | | | I_V/ϕ_V | | 0.8 | | mcd/mlm |
| Color temperature | | | T_K | | 5500 | | K |
| Angle of half intensity | | | ϕ | | ± 30 | | deg |
| Total included angle | 90 % of Total Flux Captured | | $\phi_{0.9V}$ | | 75 | | deg |
| Forward voltage | $I_F = 50 \text{ mA}, R_{thJA}=200 \text{ }^{\circ}\text{K/W}$ | | V_F | | 4.3 | 5.1 | V |
| Reverse voltage | $I_R = 10 \mu\text{A}$ | | V_R | 5 | 10 | | V |
| Junction capacitance | $V_R = 0, f = 1 \text{ MHz}$ | | C_j | | 50 | | pF |

Typical Characteristics ($T_{amb} = 25^{\circ}\text{C}$, unless otherwise specified)

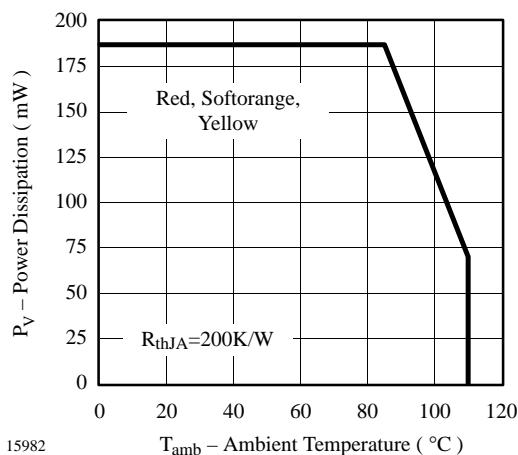


Figure 1 Power Dissipation vs. Ambient Temperature

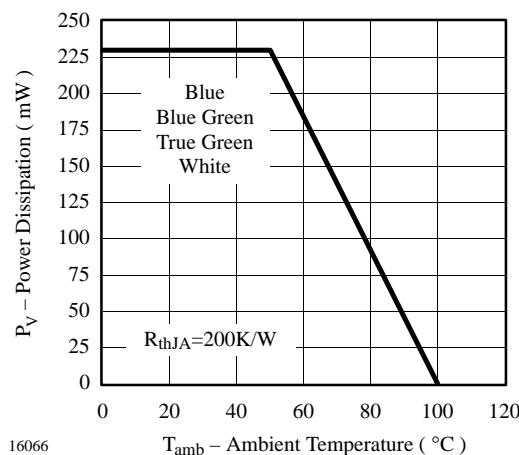


Figure 3 Power Dissipation vs. Ambient Temperature

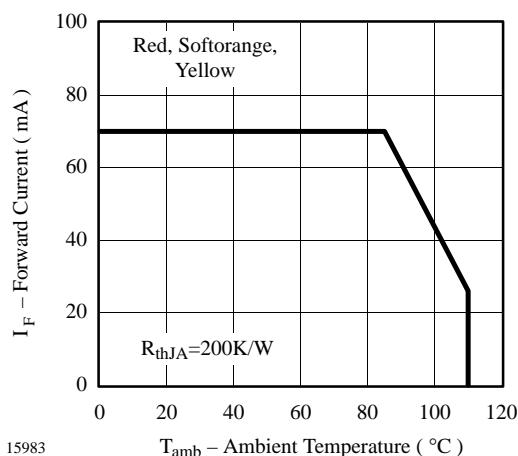


Figure 2 Forward Current vs. Ambient Temperature

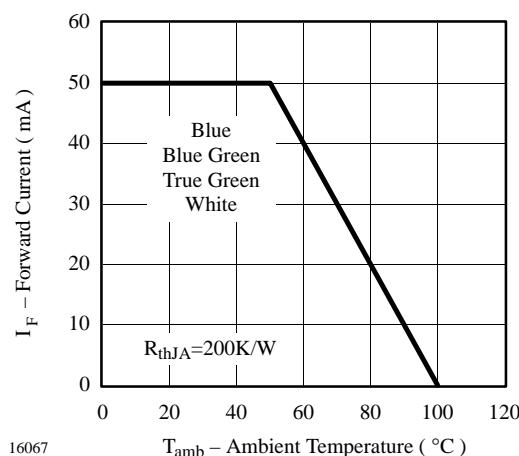
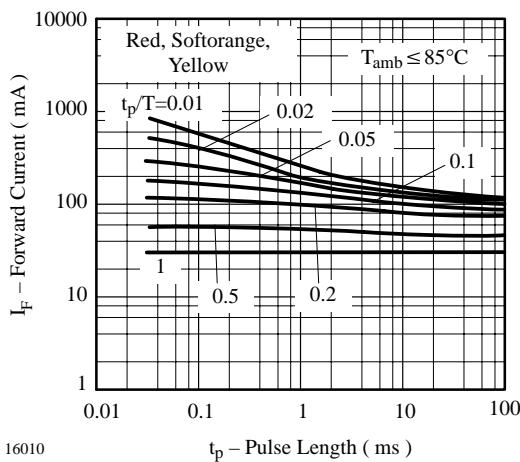
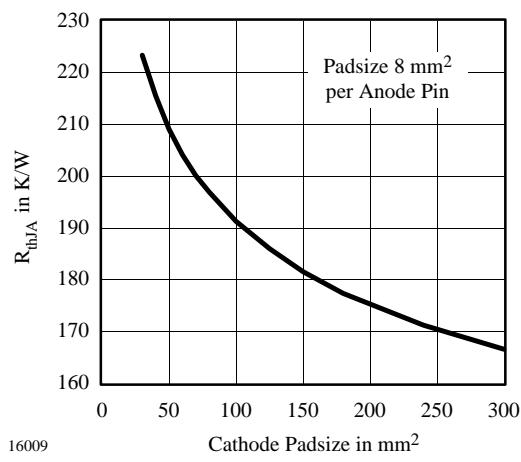


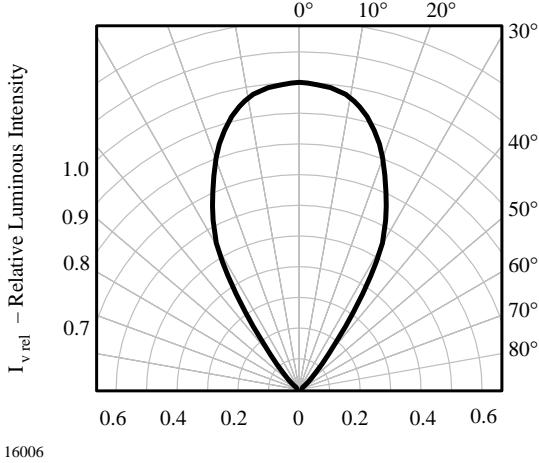
Figure 4 Forward Current vs. Ambient Temperature



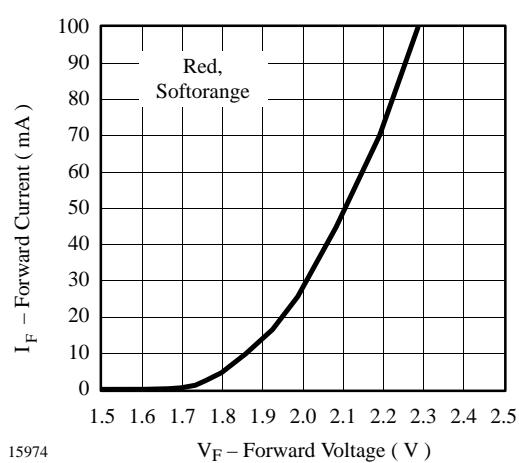
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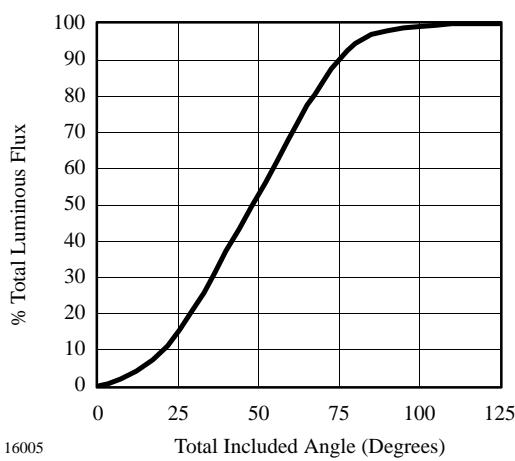
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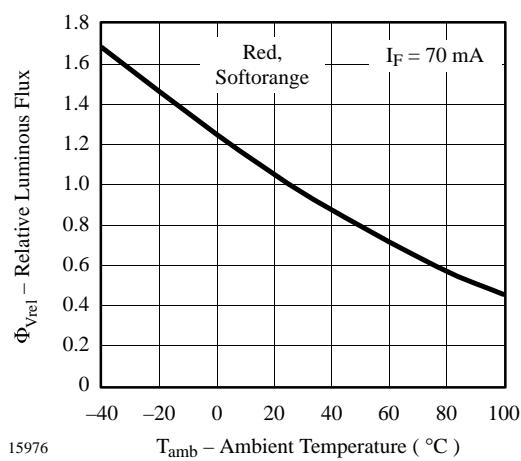
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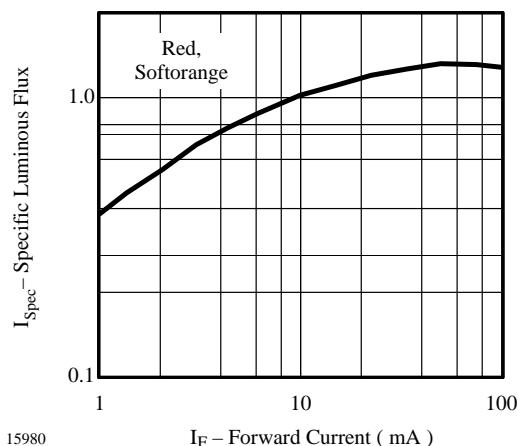
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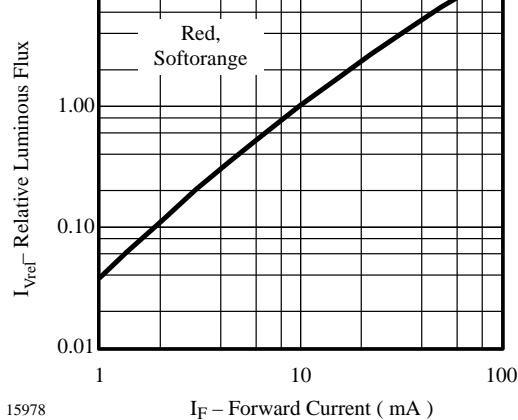
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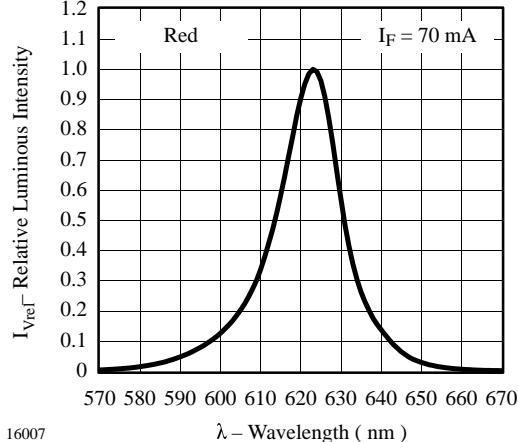


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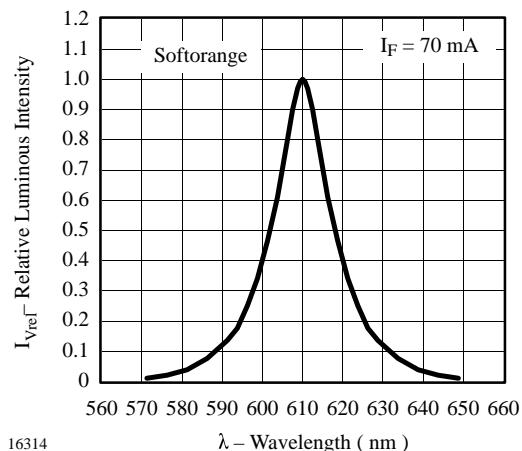
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Figure 11 Specific Luminous Flux vs. Forward Current

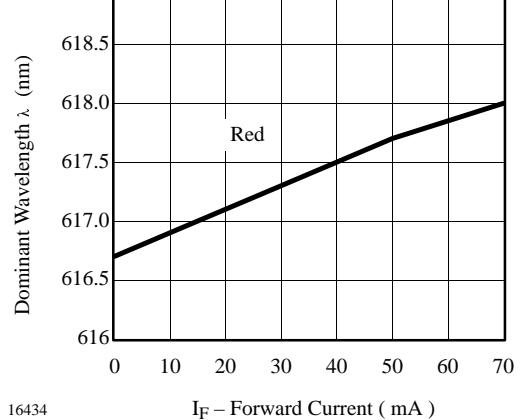


16007

Figure 13 Relative Luminous Intensity vs. Wavelength

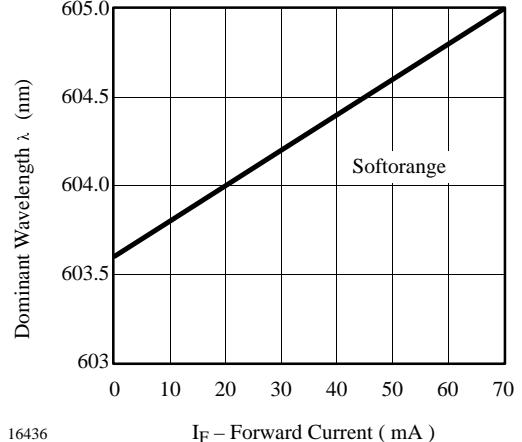


16314



16434

Figure 15 Dominant Wavelength vs. Forward Current



16436

Figure 16 Dominant Wavelength vs. Forward Current

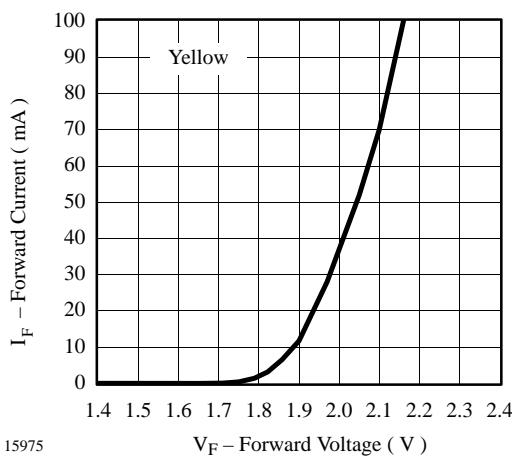


Figure 17 Forward Current vs. Forward Voltage

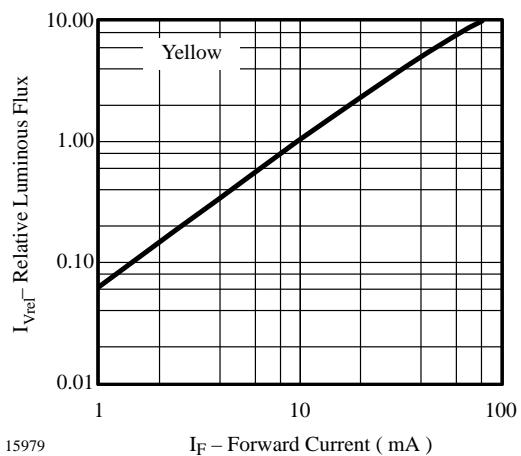


Figure 20 Relative Luminous Flux vs. Forward Current

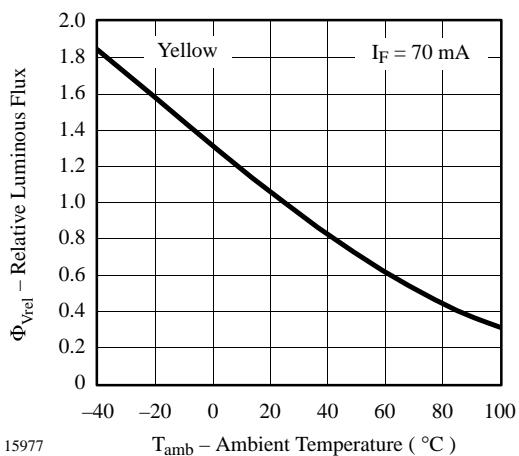


Figure 18 Rel. Luminous Flux vs. Ambient Temperature

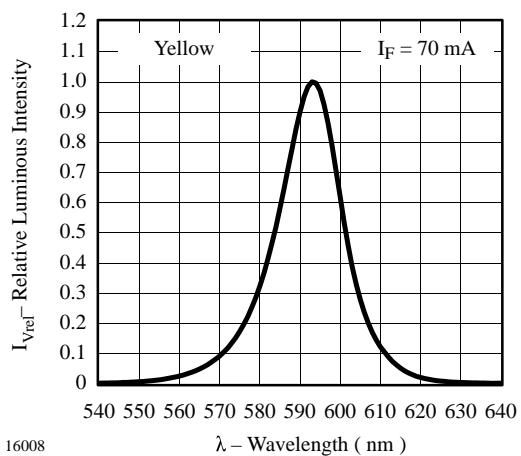


Figure 21 Relative Luminous Intensity vs. Wavelength

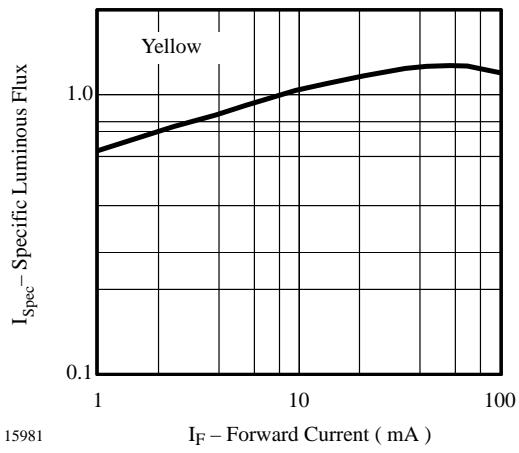


Figure 19 Specific Luminous Flux vs. Forward Current

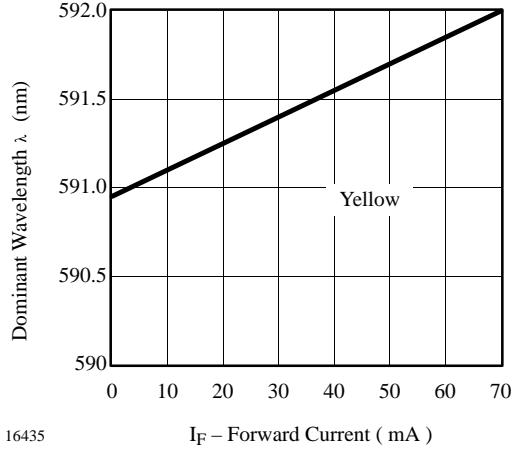
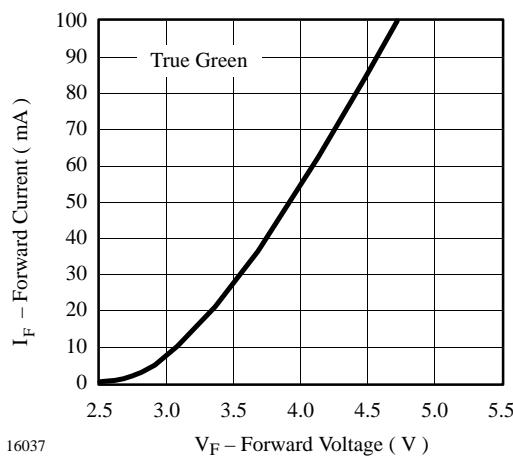
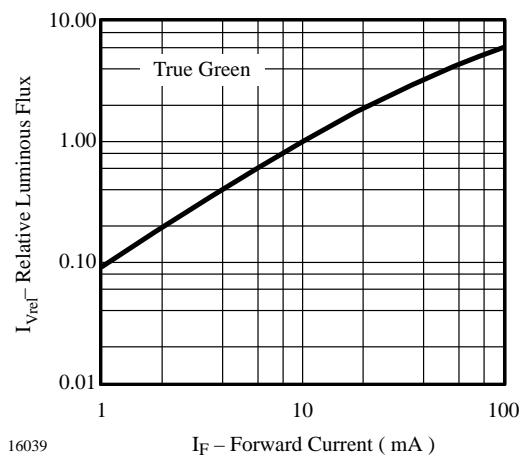


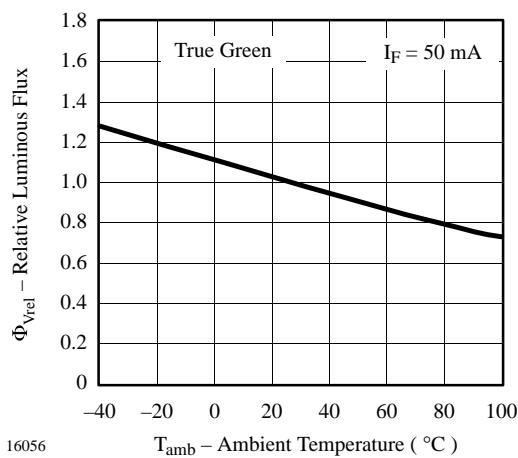
Figure 22 Dominant Wavelength vs. Forward Current



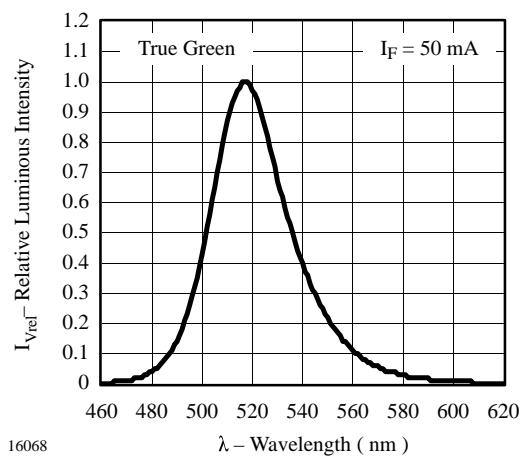
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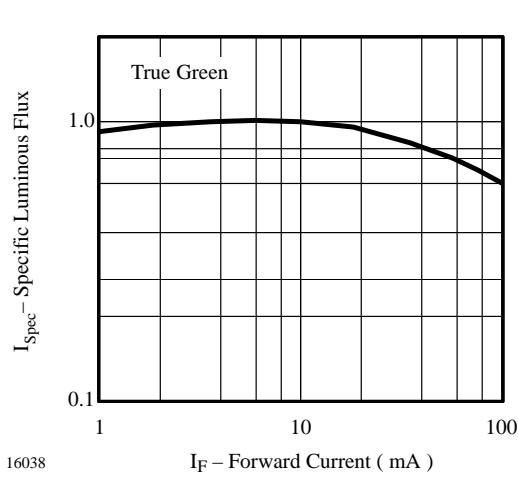
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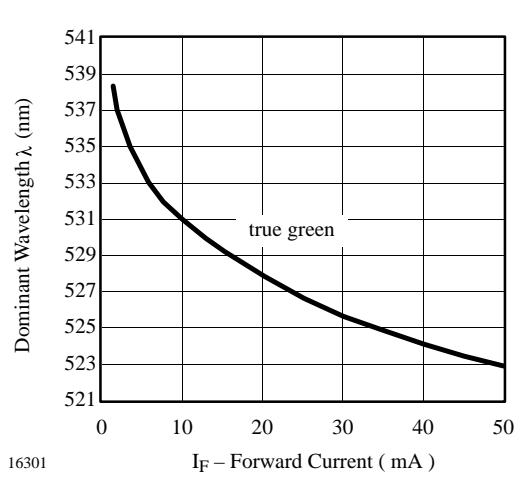
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16068



16038



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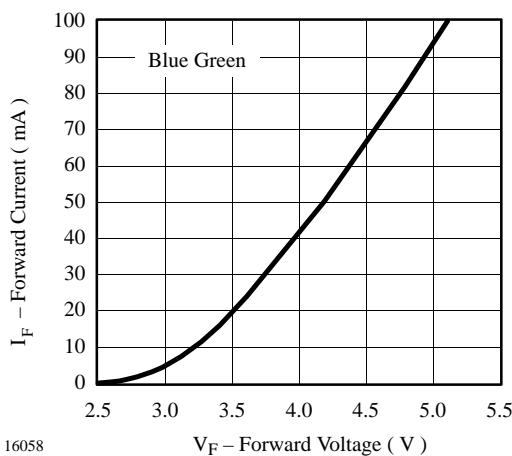


Figure 29 Forward Current vs. Forward Voltage

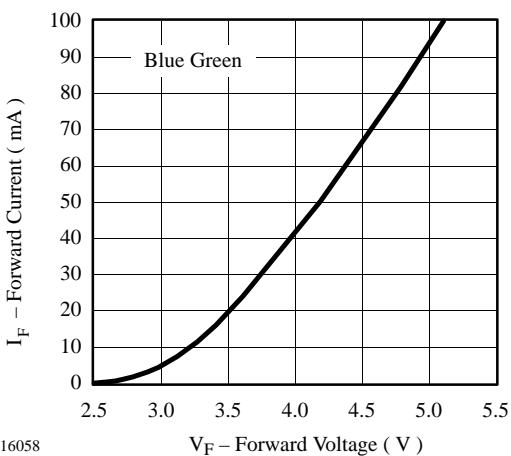


Figure 32 Forward Current vs. Forward Voltage

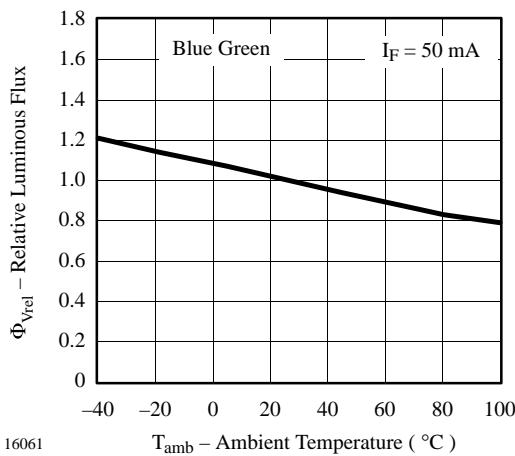


Figure 30 Rel. Luminous Flux vs. Ambient Temperature

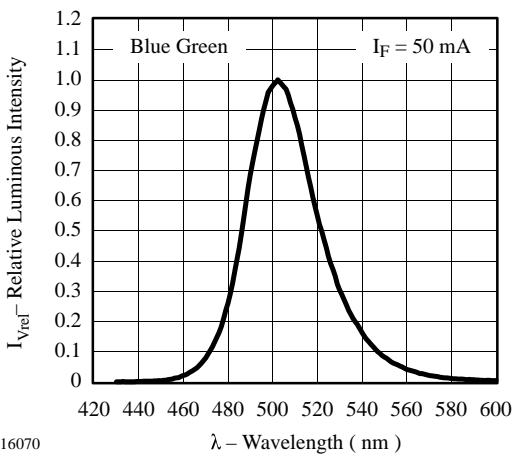


Figure 33 Relative Luminous Intensity vs. Wavelength

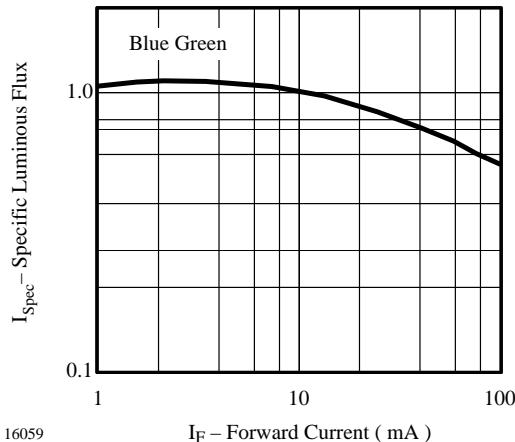


Figure 31 Specific Luminous Flux vs. Forward Current

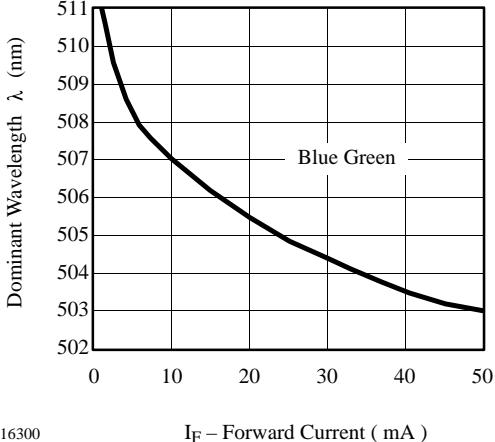


Figure 34 Dominant Wavelength vs. Forward Current

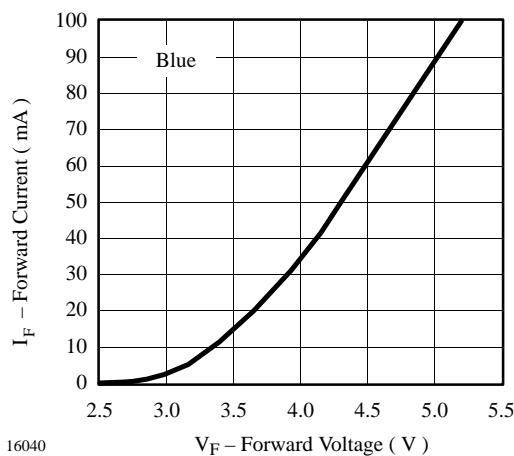


Figure 35 Forward Current vs. Forward Voltage

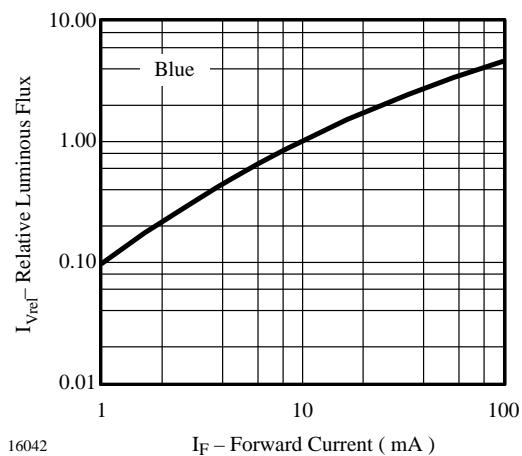


Figure 38 Relative Luminous Flux vs. Forward Current

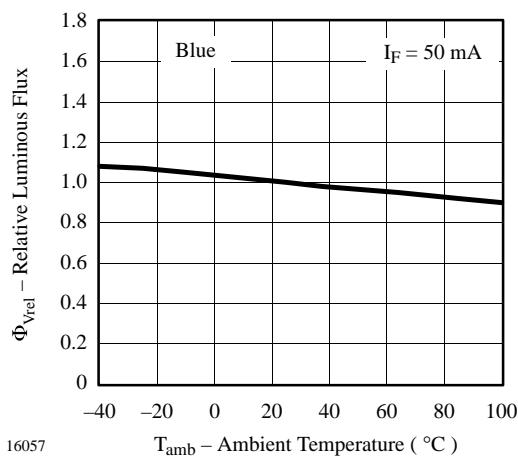


Figure 36 Rel. Luminous Flux vs. Ambient Temperature

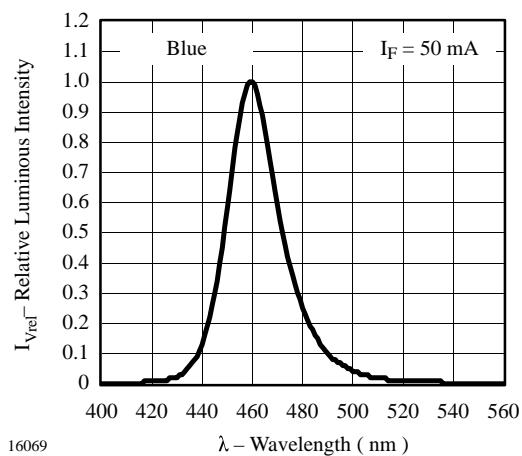


Figure 39 Relative Luminous Intensity vs. Wavelength

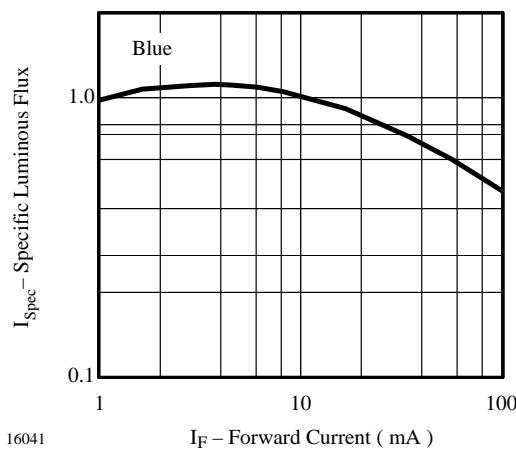


Figure 37 Specific Luminous Flux vs. Forward Current

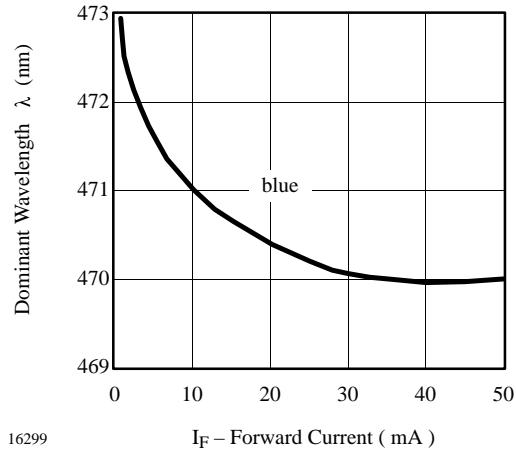


Figure 40 Dominant Wavelength vs. Forward Current

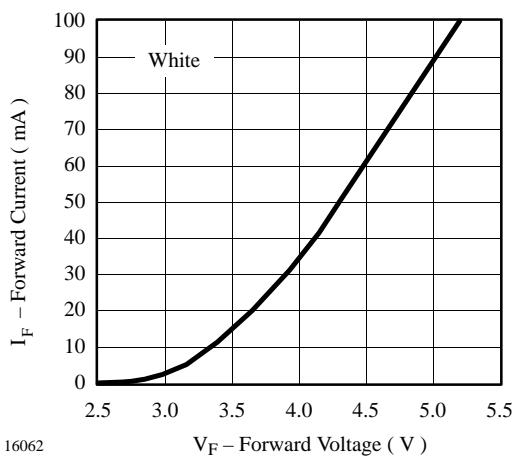


Figure 41 Forward Current vs. Forward Voltage

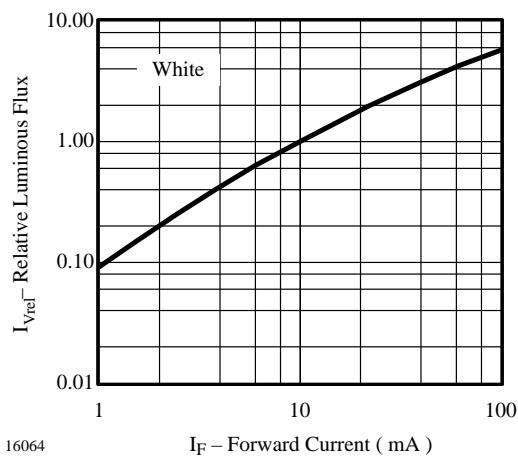


Figure 44 Relative Luminous Flux vs. Forward Current

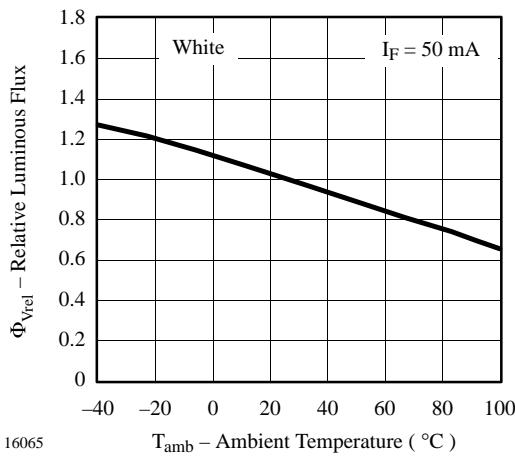


Figure 42 Rel. Luminous Flux vs. Ambient Temperature

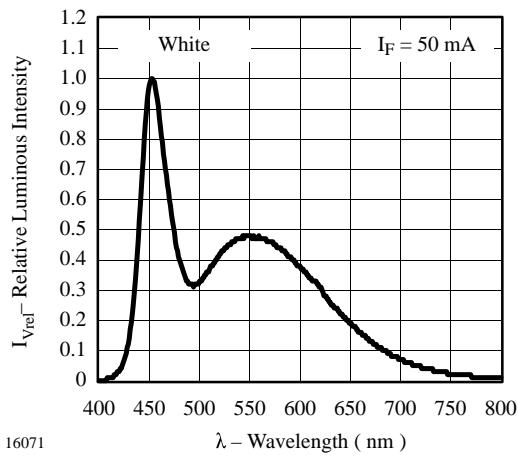


Figure 45 Relative Luminous Intensity vs. Wavelength

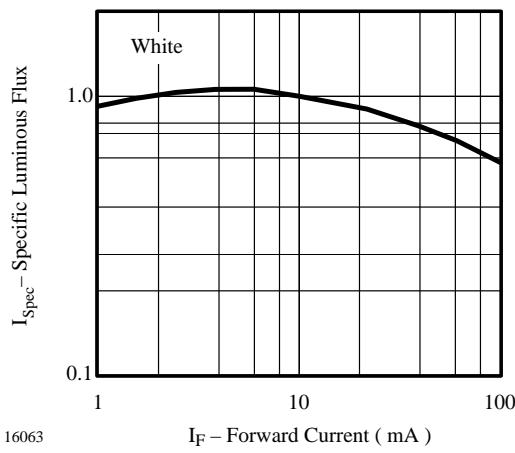


Figure 43 Specific Luminous Flux vs. Forward Current

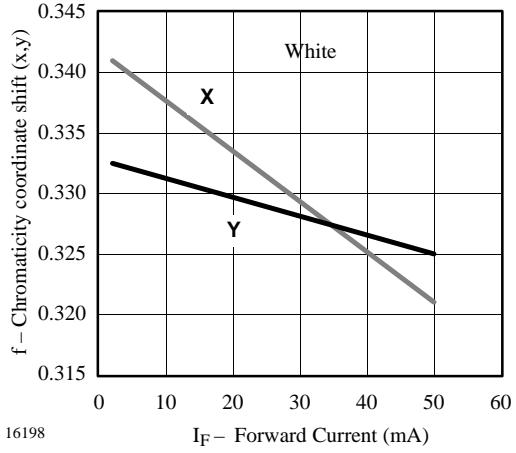
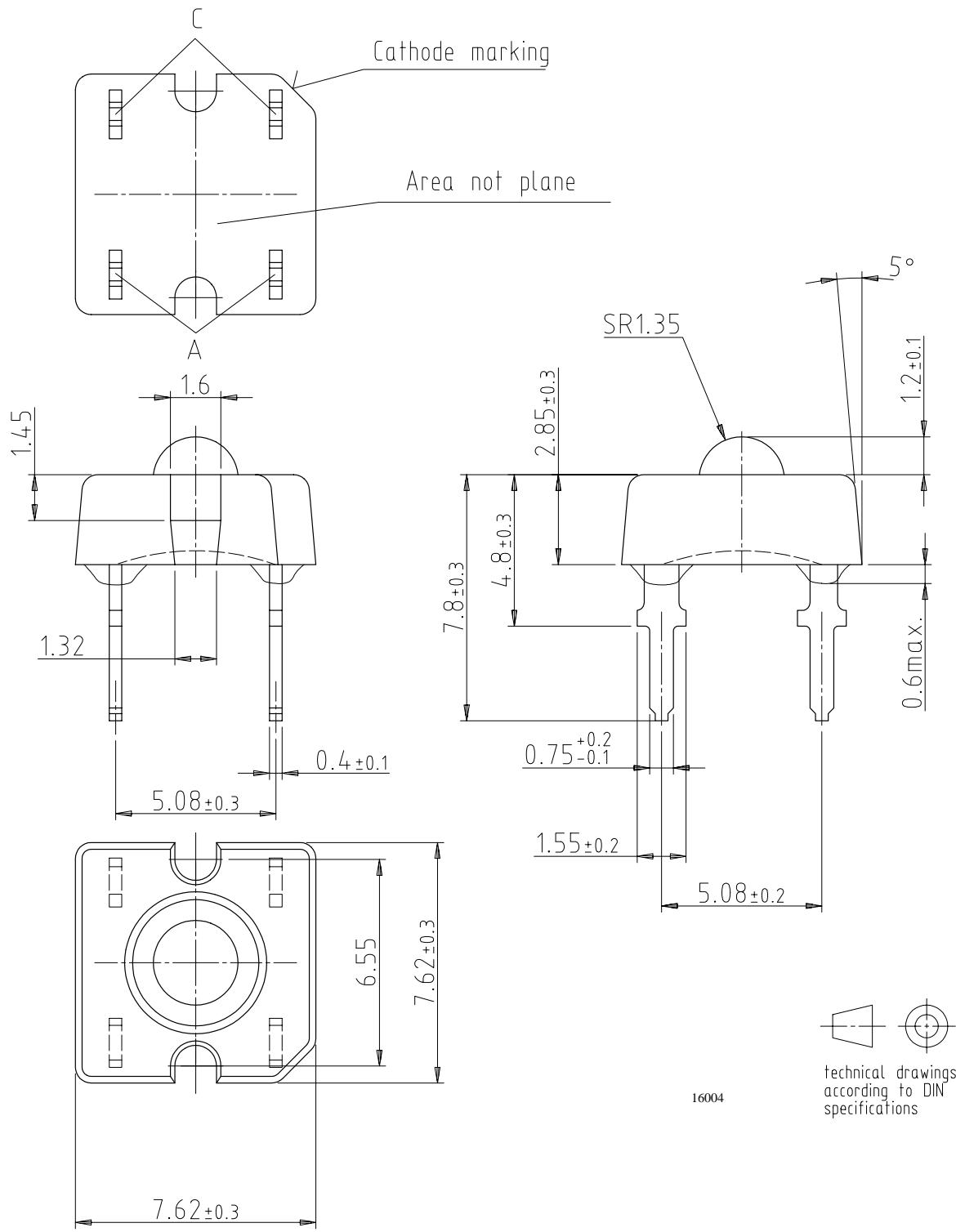


Figure 46 Chromaticity Coordinate Shift vs. Forward Current

Dimensions in mm


Ozone Depleting Substances Policy Statement

It is the policy of **Vishay Semiconductor GmbH** to

1. Meet all present and future national and international statutory requirements.
2. Regularly and continuously improve the performance of our products, processes, distribution and operating systems with respect to their impact on the health and safety of our employees and the public, as well as their impact on the environment.

It is particular concern to control or eliminate releases of those substances into the atmosphere which are known as ozone depleting substances (ODSs).

The Montreal Protocol (1987) and its London Amendments (1990) intend to severely restrict the use of ODSs and forbid their use within the next ten years. Various national and international initiatives are pressing for an earlier ban on these substances.

Vishay Semiconductor GmbH has been able to use its policy of continuous improvements to eliminate the use of ODSs listed in the following documents.

1. Annex A, B and list of transitional substances of the Montreal Protocol and the London Amendments respectively
2. Class I and II ozone depleting substances in the Clean Air Act Amendments of 1990 by the Environmental Protection Agency (EPA) in the USA
3. Council Decision 88/540/EEC and 91/690/EEC Annex A, B and C (transitional substances) respectively.

Vishay Semiconductor GmbH can certify that our semiconductors are not manufactured with ozone depleting substances and do not contain such substances.

We reserve the right to make changes to improve technical design and may do so without further notice.

Parameters can vary in different applications. All operating parameters must be validated for each customer application by the customer. Should the buyer use Vishay-Telefunken products for any unintended or unauthorized application, the buyer shall indemnify Vishay-Telefunken against all claims, costs, damages, and expenses, arising out of, directly or indirectly, any claim of personal damage, injury or death associated with such unintended or unauthorized use.

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